

# 6MBP200VEA120-50

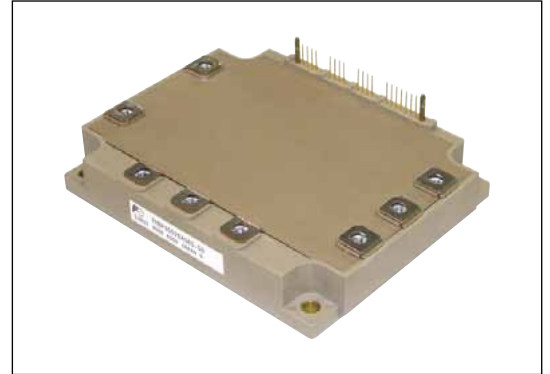
**IGBT Modules**

## IGBT MODULE (V series)

### 1200V / 200A / IPM

#### ■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



#### ■ Maximum Ratings and Characteristics

##### ● Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ , $V_{cc}=15\text{V}$ unless otherwise specified)

Items	Symbol	Min.	Max.	Units		
Collector-Emitter Voltage (*1)	$V_{CES}$	0	1200	V		
Short Circuit Voltage	$V_{SC}$	400	800	V		
Inverter	Collector Current	DC	$I_C$	-	200	A
		1ms	$I_{CP}$	-	400	A
		Duty=100% (*2)	$-I_C$	-	200	A
Collector Power Dissipation	1 device (*3)	$P_C$	-	961	W	
Brake	Collector Current	DC	$I_C$	-	-	A
		1ms	$I_{CP}$	-	-	A
	Forward Current of Diode		$I_F$	-	-	A
	Collector Power Dissipation	1 device (*3)	$P_C$	-	-	W
Supply Voltage of Pre-Driver (*4)	$V_{CC}$	-0.5	20	V		
Input Signal Voltage (*5)	$V_{in}$	-0.5	$V_{CC}+0.5$	V		
Alarm Signal Voltage (*6)	$V_{ALM}$	-0.5	$V_{CC}$	V		
Alarm Signal Current (*7)	$I_{ALM}$	-	20	mA		
Junction Temperature	$T_J$	-	150	$^\circ\text{C}$		
Operating Case Temperature	$T_{opr}$	-20	110	$^\circ\text{C}$		
Storage Temperature	$T_{stg}$	-40	125	$^\circ\text{C}$		
Solder Temperature (*8)	$T_{sol}$	-	260	$^\circ\text{C}$		
Isolating Voltage (*9)	$V_{iso}$	-	AC2500	Vrms		
Screw Torque	Terminal (M5)	-	-	-		
	Mounting (M5)	-	-	3.5	Nm	

Note \*1:  $V_{CES}$  shall be applied to the input voltage between all Collector and Emitter.

[ P1-(U,V,W,B) , P2-(U,V,W,B) , (U,V,W,B)-N1 , (U,V,W,B)-N2 ]

Note \*2: Duty= $125^\circ\text{C}/R_{th(j-c)D}/(I_F \times V_F \text{ Max.}) \times 100$

Note \*3:  $P_C=125^\circ\text{C}/R_{th(j-c)}$  (Inverter & Brake)

Note \*4:  $V_{CC}$  shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 14 and 13.

Note \*5:  $V_{in}$  shall be applied to the input voltage between terminal No.2 and 1, 6 and 5, 10 and 9, 15~18 and 13.

Note \*6:  $V_{ALM}$  shall be applied to the voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 19 and 13.

Note \*7:  $I_{ALM}$  shall be applied to the input current to terminal No.4, 8, 12 and 19.

Note \*8: Immersion time 10±1sec. 1 time

Note \*9: Terminal to base, 50/60Hz sine wave 1min. All terminals should be connected together during the test.

● Electrical Characteristics ( $T_J=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$  unless otherwise specified)

Items		Symbol	Conditions	Min.	Typ.	Max.	Units	
Inverter	Collector Current at off signal input	$I_{CES}$	$V_{CE}=1200\text{V}$	-	-	1.0	mA	
	Collector-Emitter saturation voltage (*10)	$V_{CE(sat)}$	$I_C=200\text{A}$	Terminal	-	-	2.30	V
				Chip	-	1.70	-	V
	Forward voltage of FWD (*10)	$V_F$	$I_F=200\text{A}$	Terminal	-	-	2.75	V
Chip				-	2.10	-	V	
Brake	Collector Current at off signal input	$I_{CES}$	-	-	-	-	mA	
	Collector-Emitter saturation voltage (*10)	$V_{CE(sat)}$	-	-	-	-	V	
			-	-	-	-	V	
Forward voltage of FWD (*10)	$V_F$	-	-	-	-	V		
		-	-	-	-	V		
Switching time	$t_{on}$	$V_{DC}=600\text{V}$ , $T_J=125^\circ\text{C}$ , $I_C=200\text{A}$		1.1	-	-	$\mu\text{s}$	
	$t_{off}$			-	-	2.1	$\mu\text{s}$	
	$t_{rr}$	$V_{DC}=600\text{V}$ , $I_F=200\text{A}$		-	-	0.3	$\mu\text{s}$	
Supply current of P-side pre-driver (per one unit)		$I_{cop}$	Switching Frequency= 0-15kHz $T_C=-20\sim 110^\circ\text{C}$	-	-	42	mA	
Supply current of N-side pre-driver		$I_{con}$		-	-	126	mA	
Input signal threshold voltage		$V_{in(th)(on)}$	$V_{in}-\text{GND}$	ON	1.2	1.4	1.6	V
		$V_{in(th)(off)}$		OFF	1.5	1.7	1.9	V
Over Current Protection Level	Inverter	$I_{OC}$	$T_J=125^\circ\text{C}$	300	-	-	A	
	Brake			-	-	-	A	
Over Current Protection Delay time		$t_{dOC}$	$T_J=125^\circ\text{C}$	-	5	-	$\mu\text{s}$	
Short Circuit Protection Delay time		$t_{SC}$	$T_J=125^\circ\text{C}$	-	2	3	$\mu\text{s}$	
IGBT Chips Over Heating Protection Temperature Level		$T_{J(OH)}$	Surface of IGBT Chips	150	-	-	$^\circ\text{C}$	
Over Heating Protection Hysteresis		$T_{JH}$		-	20	-	$^\circ\text{C}$	
Under Voltage Protection Level		$V_{UV}$		11.0	-	12.5	V	
Under Voltage Protection Hysteresis		$V_H$		0.2	0.5	-	V	
Alarm Signal Hold Time		$t_{ALM(OC)}$	ALM-GND $T_C=-20\sim 110^\circ\text{C}$	$V_{CC}\geq 10\text{V}$	1.0	2.0	2.4	ms
		$t_{ALM(UV)}$			2.5	4.0	4.9	ms
		$t_{ALM(TJOH)}$			5.0	8.0	11.0	ms
Resistance for current limit		$R_{ALM}$		960	1265	1570	$\Omega$	

Note \*10: The Max value is a case where it measures from P2-(U,V,W,B) , (U,V,W,B)-N2.

● Thermal Characteristics ( $T_c = 25^\circ\text{C}$ )

Items			Symbol	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance (*11)	Inverter	IGBT	$R_{th(j-c)Q}$	-	-	0.130	$^\circ\text{C}/\text{W}$
		FWD	$R_{th(j-c)D}$	-	-	0.195	$^\circ\text{C}/\text{W}$
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	-	$^\circ\text{C}/\text{W}$
		FWD	$R_{th(j-c)D}$	-	-	-	$^\circ\text{C}/\text{W}$
Case to Fin Thermal Resistance with Compound			$R_{th(c-f)}$	-	0.05	-	$^\circ\text{C}/\text{W}$

Note \*11: For 1device, the measurement point of the case is just under the chip.

● Noise Immunity ( $V_{DC}=600\text{V}$ ,  $V_{CC}=15\text{V}$ )

Items	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width $1\mu\text{s}$ , polarity $\pm 10$ min. Judge : no over-current, no miss operating	$\pm 2.0$	-	-	kV

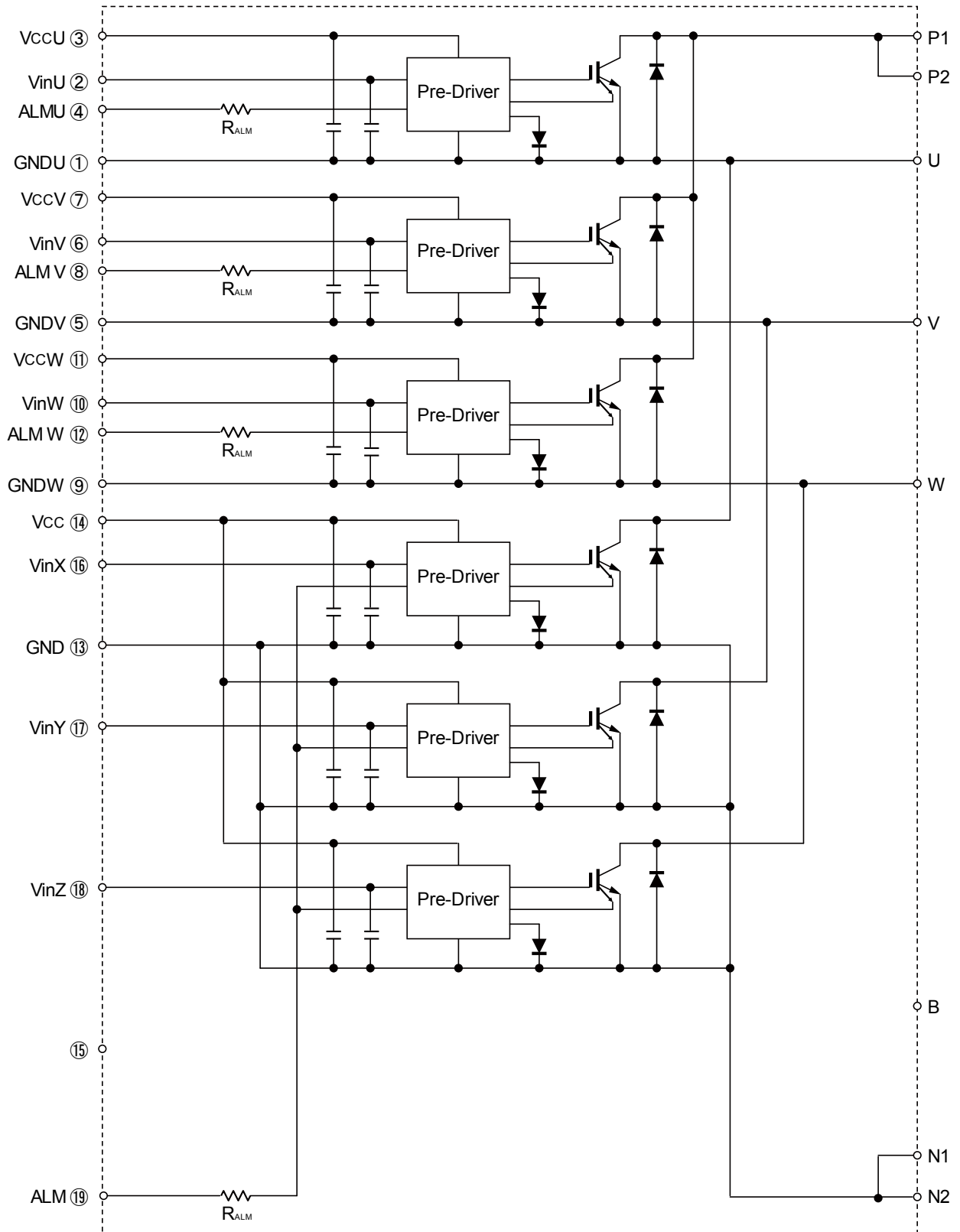
● Recommended Operating Conditions

Items	Symbol	Min.	Typ.	Max.	Units
DC Bus Voltage	$V_{DC}$	-	-	800	V
Power Supply Voltage of Pre-Driver	$V_{CC}$	13.5	15.0	16.5	V
Switching frequency of IPM	$f_{SW}$	-	-	20	kHz
Arm shoot through blocking time for IPM's input signal	$t_{dead}$	1.0	-	-	$\mu\text{s}$
Screw Torque (M5)	-	2.5	-	3.5	Nm

● Weight

Items	Symbol	Min.	Typ.	Max.	Units
Weight	$W_t$	-	940	-	g

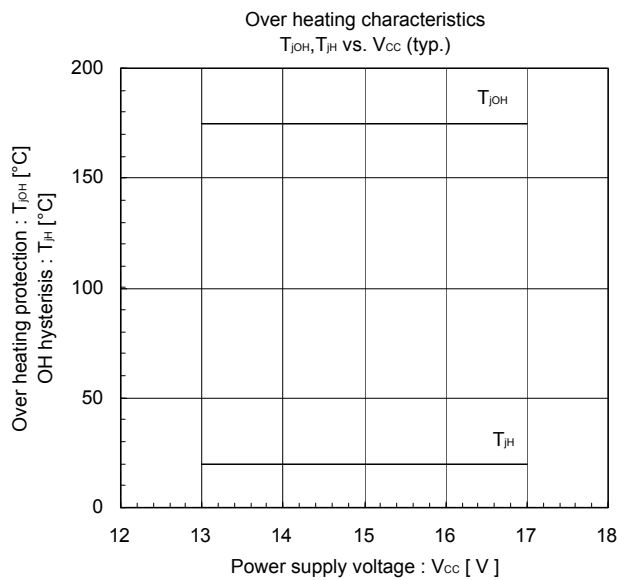
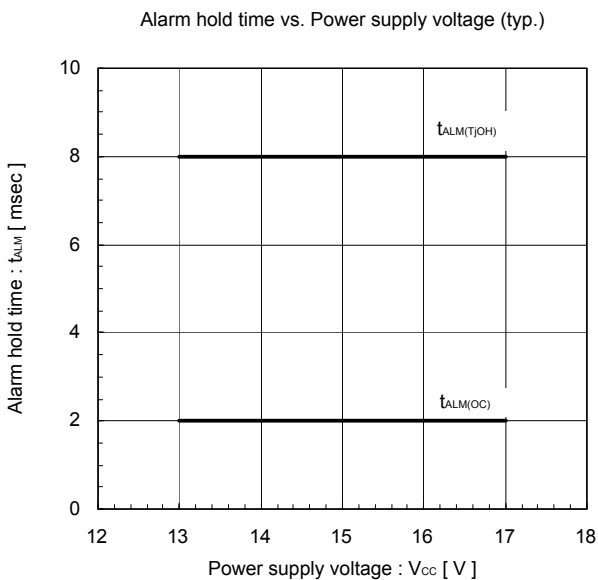
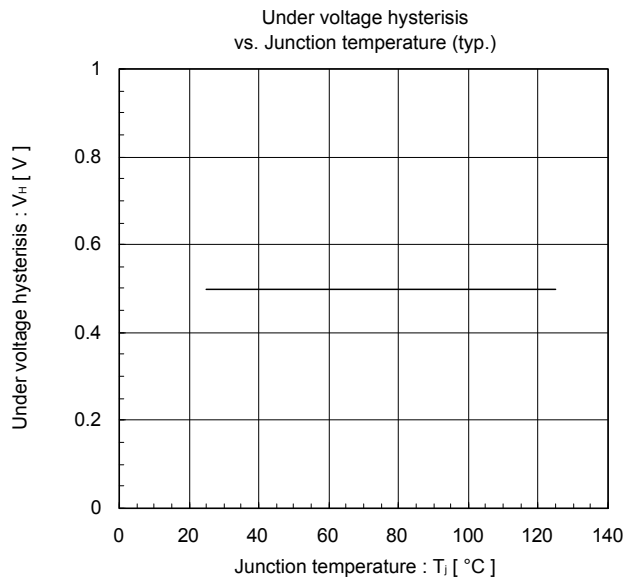
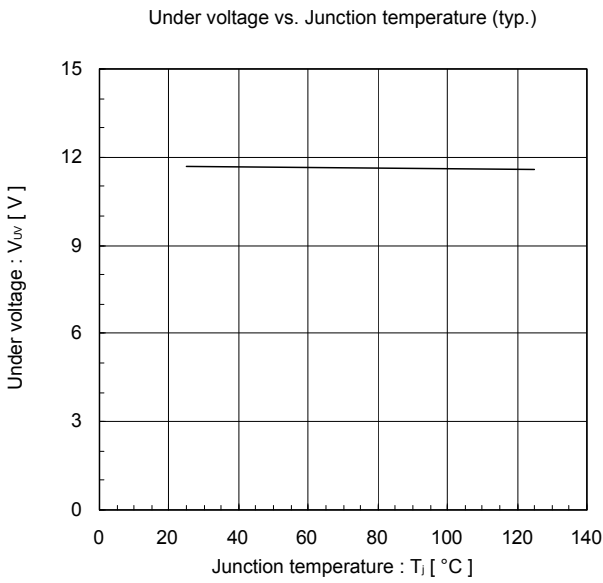
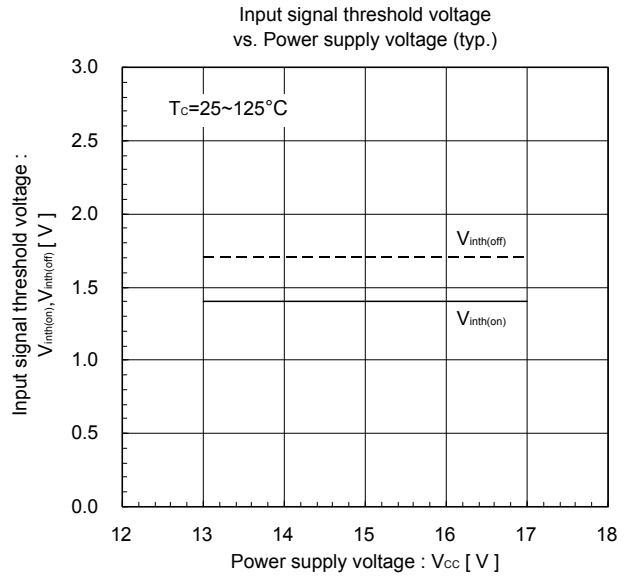
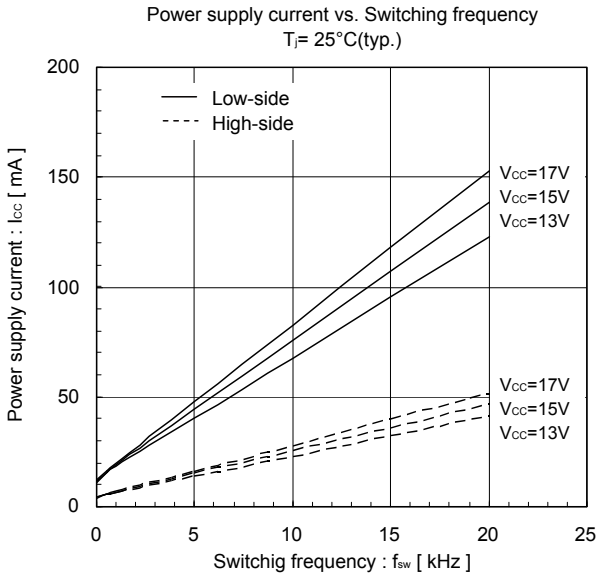
■ Block Diagram



Pre-drivers include following functions

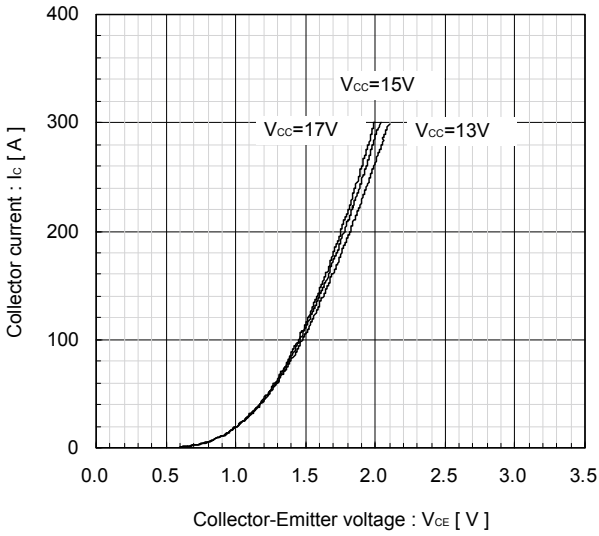
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

■ Characteristics (Representative)

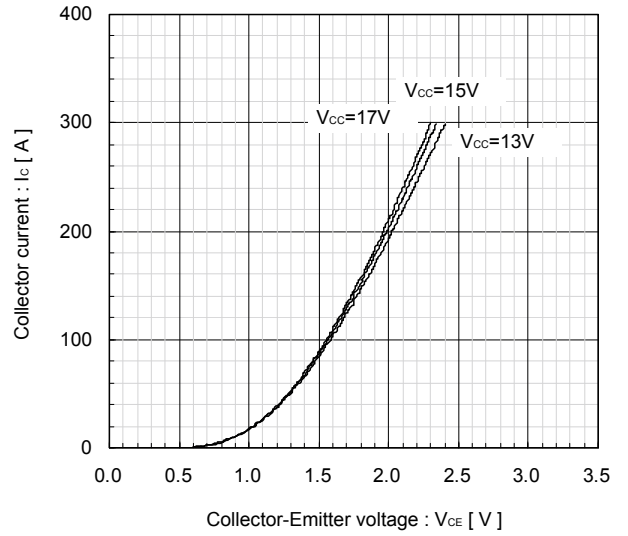


Inverter

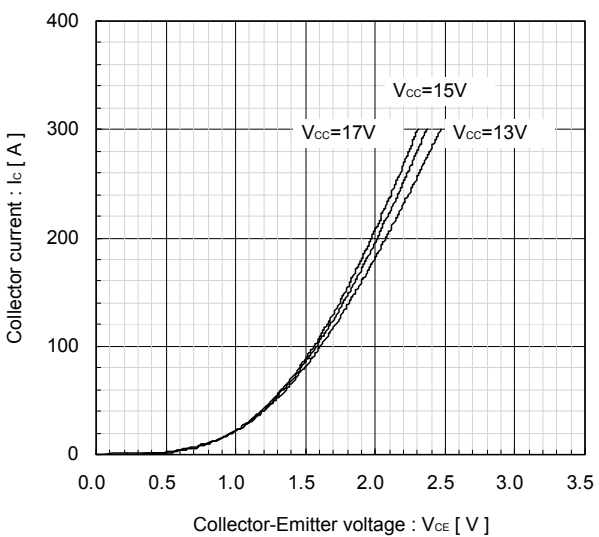
Collector current vs. Collector-Emitter voltage  
 $T_J=25^\circ\text{C}$ [Chip] (typ.)



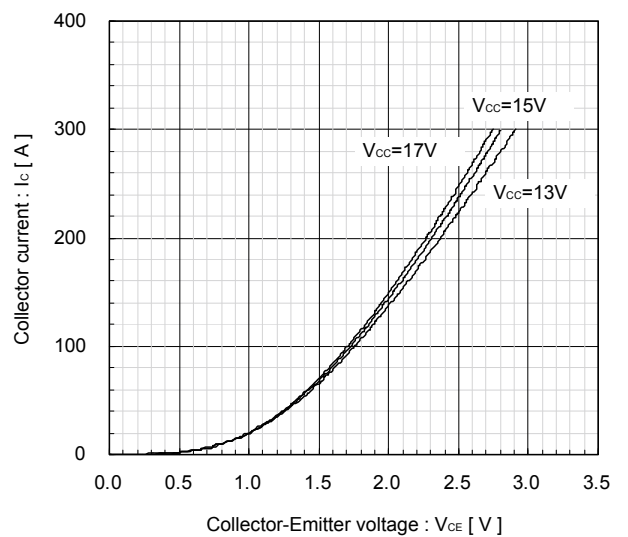
Collector current vs. Collector-Emitter voltage  
 $T_J=25^\circ\text{C}$ [Terminal] (typ.)



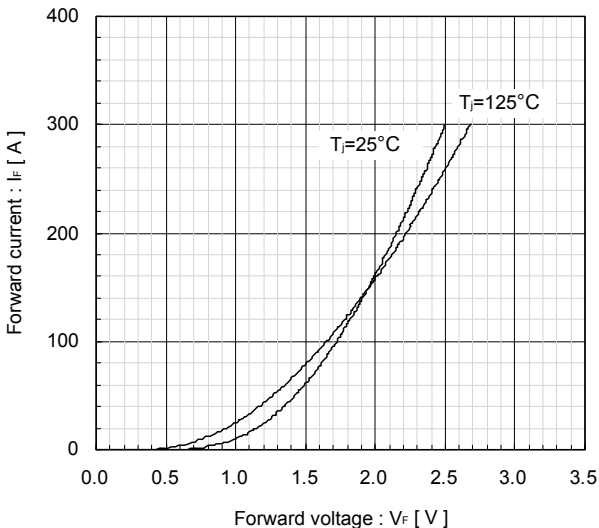
Collector current vs. Collector-Emitter voltage  
 $T_J=125^\circ\text{C}$ [Chip] (typ.)



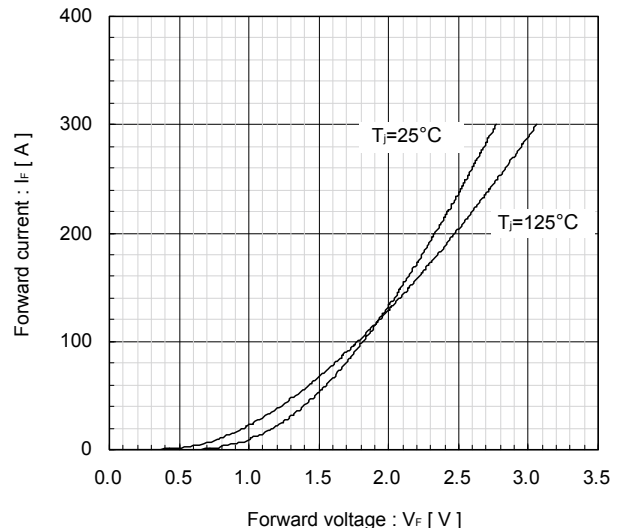
Collector current vs. Collector-Emitter voltage  
 $T_J=125^\circ\text{C}$ [Terminal] (typ.)



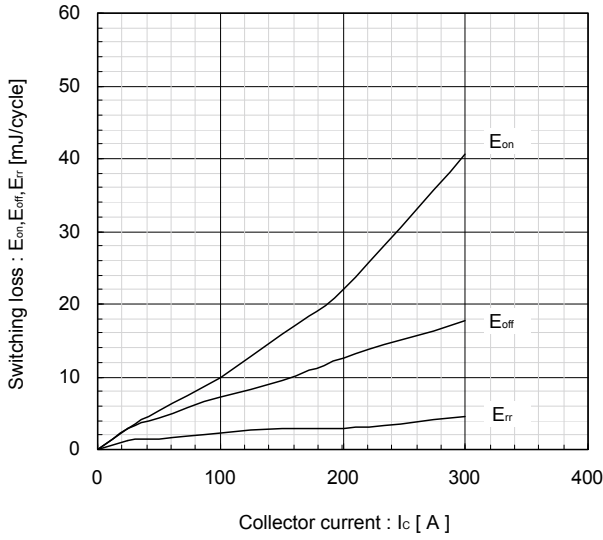
Forward current vs. Forward voltage  
 [Chip] (typ.)



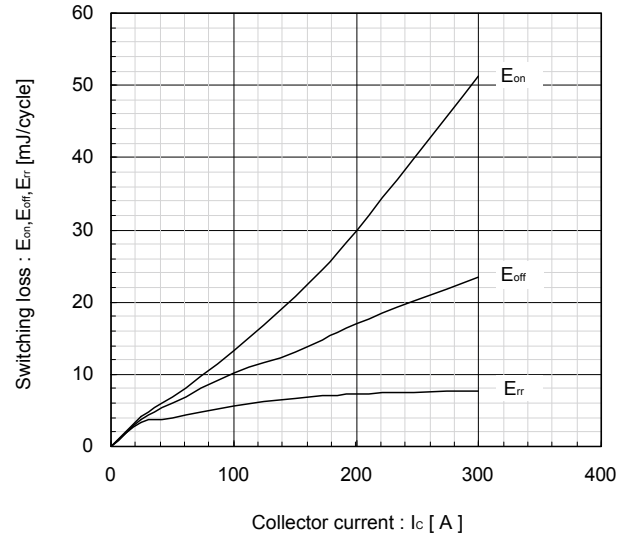
Forward current vs. Forward voltage  
 [Terminal] (typ.)



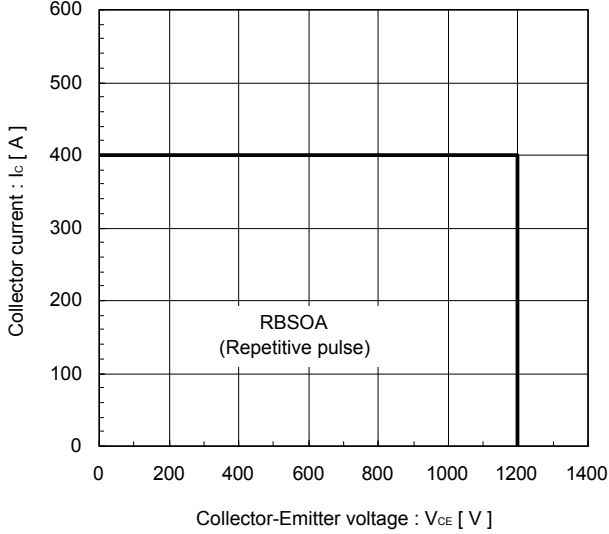
Switching Loss vs. Collector Current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_j=25^\circ C$



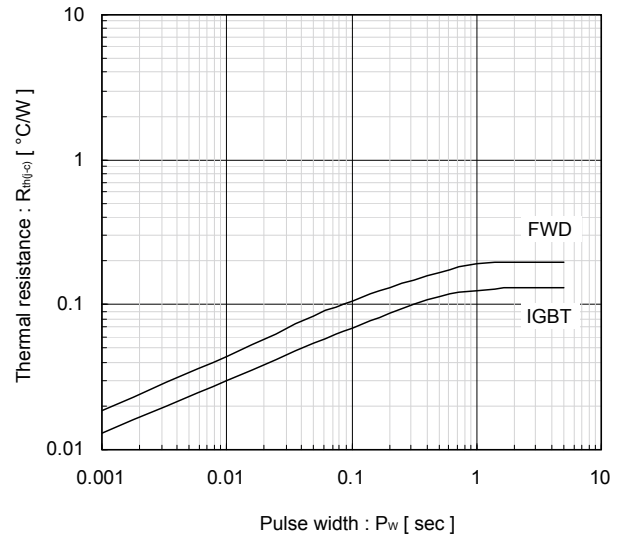
Switching Loss vs. Collector Current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_j=125^\circ C$



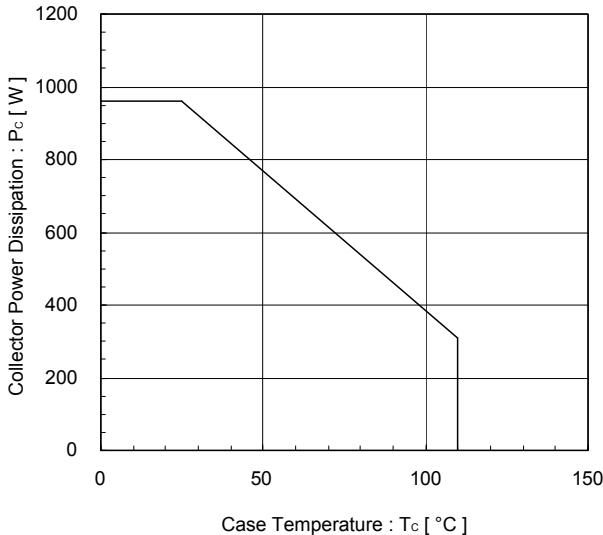
Reversed biased safe operating area  
 $V_{CC}=15V, T_j \leq 125^\circ C$  [Main Terminal] (min.)



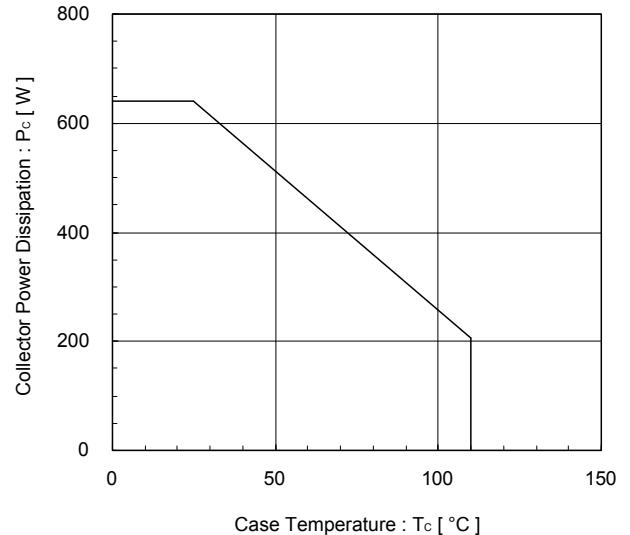
Transient thermal resistance (max.)



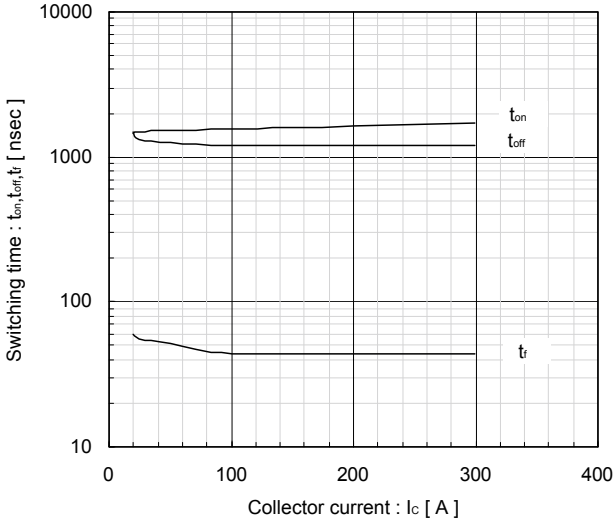
Power derating for IGBT (max.)  
 [per device]



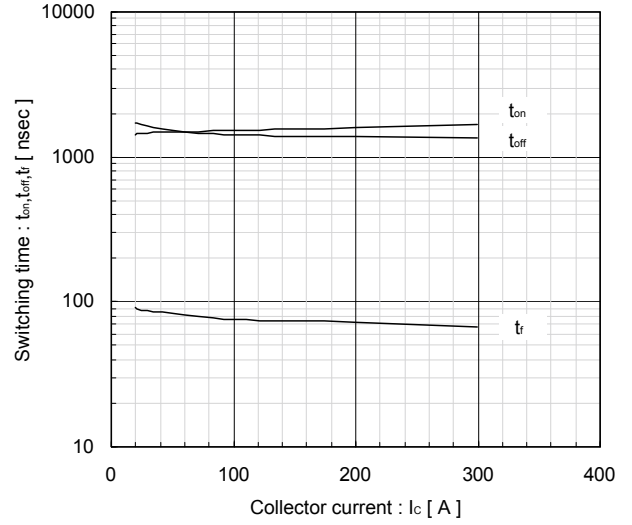
Power derating for FWD (max.)  
 [per device]



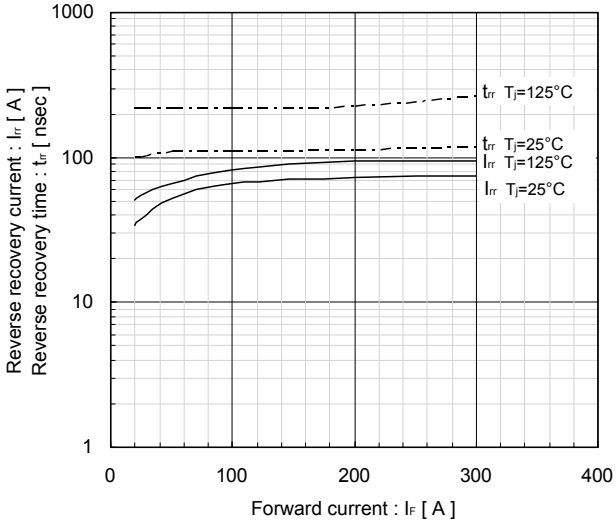
Switching time vs. Collector current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_J=25^\circ C$



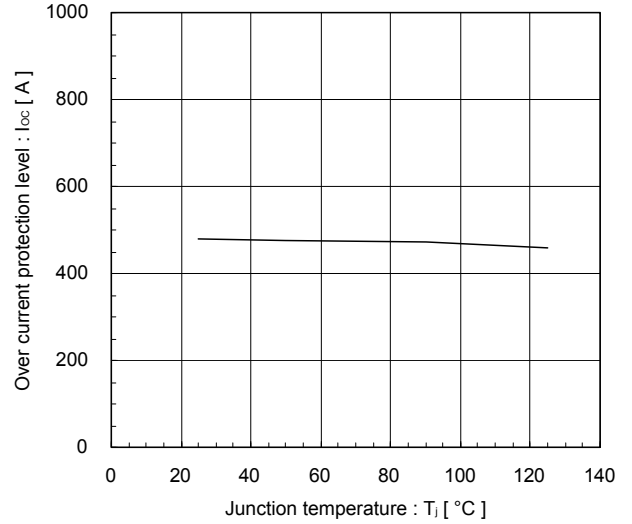
Switching time vs. Collector current (typ.)  
 $V_{DC}=600V, V_{CC}=15V, T_J=125^\circ C$



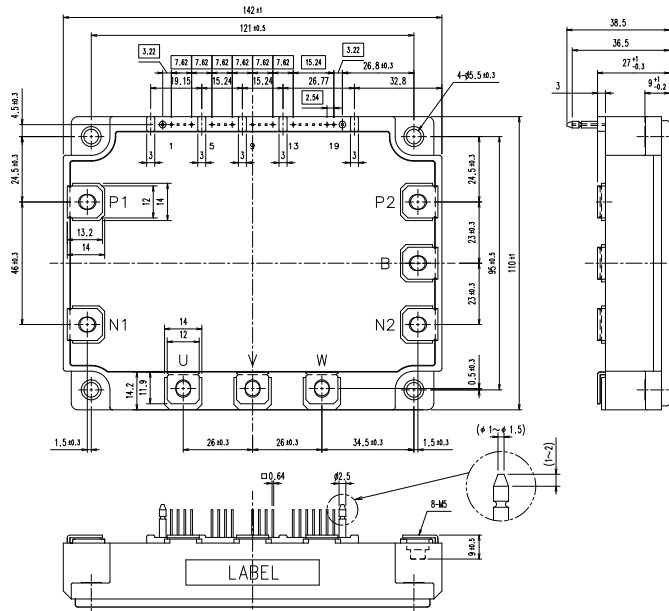
Reverse recovery characteristics (typ.)  
 $t_{rr}, I_{rr}$  vs.  $I_F$



Over current protection vs. Junction temperature (typ.)  
 $V_{CC}=15V$



■ Outline Drawings, mm



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## IGBT Modules

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4 技术资料	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/">www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/</a>
5 安装说明书	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/">www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/</a>
6 IGBT 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/</a>
7 AT-NPC 3-Level 损耗模拟软件	<a href="http://www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation_3level/">www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation_3level/</a>
8 富士电机技报	<a href="http://www.fujielectric.com.cn/products/semiconductor/journal/">www.fujielectric.com.cn/products/semiconductor/journal/</a>
9 产品咨询	<a href="http://www.fujielectric.com.cn/products/semiconductor/contact/">www.fujielectric.com.cn/products/semiconductor/contact/</a>
10 产品更改和停产信息	<a href="http://www.fujielectric.com.cn/products/semiconductor/discontinued/">www.fujielectric.com.cn/products/semiconductor/discontinued/</a>